Why magnetic monopole becomes dyon in topological insulators

Naoto Kan (Osaka University)

Based on collaborations with Shoto Aoki, Hidenori Fukaya, Mikito Koshino, Yoshiyuki Matsuki (Osaka U.), arXiv:2304.13954 [cond-mat.mes-hall].

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— We expect that the monopole is observed as a dyon with the electric chage $q_e = -1/2$, because of the Witten effect [Witten ('79)].

EFT of topological insulator and Witten effect

A topological insulator: the bulk is the insulator (gapped), but the edge is the gapless. The effective theory of the T-symmetric topological insulator is described by the $\theta=\pi$ vacuum. In the presence of the magnetic monopole, the θ -term is given by

$$L_{\theta} = \frac{\theta}{8\pi^2} \int d^3x \, \boldsymbol{E} \cdot \boldsymbol{B} = -\frac{q_m}{2} \int d^3x \, A^0 \delta^{(3)}(\boldsymbol{r}).$$

This implies that there is a particle with electric charge $q_e=-q_m/2$ which is coupled to the A^0 potential.

The monopole with $q_m = 1$ obtains the electric charge $q_e = -1/2$.

The effective theory description above is quite simple, but can't answer to the following questions:

- (1) what is the origin of the electric charge? (must be electrons)
- (2) if the origin is the electrons, why is it bound to monopole?
- (3) why is the electric charge fractional?

In this our work [Aoki, Fukaya, Kan, Koshino Matsuki ('23)], we try to give answers to the questions from in terms of a microscopic description.

A microscopic description

Naively a UV description of the system is given by the Dirac Hamiltonian with a mass m<0 [Yamagishi ('83)]:

$$H = \gamma_0 \left(\gamma_i \left(\partial_i - i A_i \right) + m \right),\,$$

where $\gamma_0 = \sigma_3 \otimes \mathbf{1}$ and $\gamma_i = \sigma_1 \otimes \sigma_i$.

In addition to J^2 and J_3 , there is an operator that commutes with H; $[H,\sigma_3\otimes D^{S^2}]=0$, where we define the "spherical" operator

$$D^{S^2} := \sigma_i \left(L_i + \frac{n}{2} \frac{x_i}{r} \right) + 1, \quad L_i = -i \epsilon_{ijk} x_j \left(\partial_k - i A_k \right) - n \frac{x_i}{2r},$$

Physical meanings of the operator are explained later.

We find the normalizable zero-mode (E=0) solution localized at the monopole (r=0) with j=|n/2|-1/2:

$$\psi_{j,j_3,0} = \frac{C_{j,j_3,0}}{r} \exp(-|m|r) \begin{pmatrix} 1\\ \operatorname{sign}(m)\operatorname{sign}(n) \end{pmatrix} \otimes \chi_{j,j_3,0}(\theta,\phi),$$

where $D^{S^2}\chi_{j,j_3,0}(\theta,\phi) = 0$.

- 1. No difference between the positive and negative mass in the solution. The Witten effect predicts the dyon appear only in the topological insulator (m < 0). The solution can't explain it w/o imposing "the chiral boundary condition" by hand.
- 2. Why does the electric charge become $q_e = -1/2$?

Regularized Dirac equation

We consider the "regularized" Dirac Hamiltonian:

$$H_{\text{reg}} = \gamma_0 \left(\gamma^i D_i + m + \frac{D_i^{\dagger} D^i}{M_{\text{PV}}} \right).$$

We can interpret the additional "Wilson term" as a reg. eff., since

$$Z = \det\left(\frac{D+m}{D+M_{\text{PV}}}\right),$$

$$= \det\left[\frac{1}{M_{\text{PV}}}\left(D+m+\frac{1}{M_{\text{PV}}}D^{\dagger}_{\mu}D^{\mu} + \mathcal{O}(1/M_{\text{PV}}^{2}, m/M_{\text{PV}}, F_{\mu\nu}/M_{\text{PV}})\right)\right].$$

in the Pauli–Villars reg., where $M_{\rm PV}(>0)$ is the PV mass.

Since the Laplacian $D_i^{\dagger}D^i$ is always positive, the mass shift due to the Wilson term is always positive when we take $M_{\rm PV}$ positive.

For m<0 (or inside topological insulators), it is possible to locally flip the sign of the "effective" mass

$$m < 0 \rightarrow m_{\text{eff}} = m + \frac{D_i^{\dagger} D^i}{M_{\text{PV}}} \sim m + \frac{1}{M_{\text{PV}} r_1^2} > 0,$$

when the magnetic flux is concentrated in the region $r < r_1$.

It's implies that the inside region $r < r_1$ becomes a normal insulator, and the spherical domain-wall is dynamically created and the chiral edge-mode appears on it! (It doesn't happen in the normal insulator with m>0.)

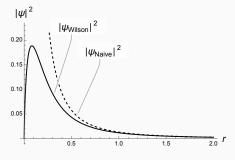
The regularized Hamiltonian is

$$H_{\text{reg}} = \begin{pmatrix} m - D_i D_i / M_{\text{PV}} & \sigma_i \left(\partial_i - i A_i \right) \\ -\sigma_i \left(\partial_i - i A_i \right) & -m + D_i D_i / M_{\text{PV}} \end{pmatrix},$$

The analytical solution of the zero-mode for $r_1 \rightarrow 0$ is given by

$$\psi_{j,j_3}^{\text{mono}} = \frac{Be^{-M_{\text{PV}}r/2}}{\sqrt{r}} I_{\nu}(\kappa r) \begin{pmatrix} 1\\ -\text{sign}(n) \end{pmatrix} \otimes \chi_{j,j_3,0}(\theta,\phi),$$

where
$$\nu = \sqrt{2|n|+1}/2$$
, and $\kappa = M_{\rm PV}\sqrt{1+4m/M_{\rm PV}}/2$.



The plot with n=1, m=-0.1, $M_{\rm PV}=10$.

- The solution ψ_{Wilson} coincides with ψ_{Naive} for large r.
- A peak at $r=|n|/(2M_{\rm PV})\sim 1/M_{\rm PV}$ is the (spherical) domain-wall.
- D^{S^2} is the Dirac operator on the spherical domain-wall created around the monopole!

The Atiyah–Singer index theorem and the half-integral charge

The 2D chirality is

$$\sigma_r \chi_{j,j_3,0}(\theta,\phi) = s \chi_{j,j_3,0}(\theta,\phi), \quad s := sign(n),$$

and # of the degeneracy is 2j + 1 = |n|. Then the Dirac index is

$$\operatorname{Ind} D^{S^2} = n.$$

On the other hand, the topological index is

$$\frac{1}{4\pi} \int_{S^2} d^2x \epsilon^{\mu\nu} F_{\mu\nu} = n.$$

Stability of the zero modes on the domain-wall is topologically protected by the AS index theorem.

So far, we considered a \mathbb{R}^3 space, but in order to discuss topological feature of the fermion zero mode, we also need an IR regularization, such as the one-point compactification, S^3 .

Then the topological insulator region with $(m_{\rm eff} < 0)$ has topology of a disk with a small S^2 boundary at $r = r_1$.

However, due to the cobordism invariance of the AS index,

$$\int_{\partial M} F = \int_{M} dF = 0,$$

the disk is not possible.



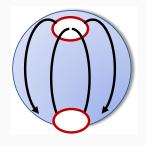
A resolution is: to create another domain-wall at, say, $r=r_0$, outside of the topological insulator.

Another zero-modes are localized at the outside domain-wall, and the index is kept trivial:

$$0 = \int_{M} dF = \int_{\Sigma_{\text{mono}}} F + \int_{\Sigma_{\text{out}}} F,$$

where $\partial M = \Sigma_{\text{mono}} \cup \Sigma_{\text{out}}$.

Then the 50% of the zero-mode state is located at the monopole, while the other 50% is sit at the domain-wall.

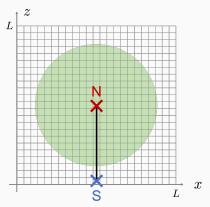


Thus the dressed electric charge of the monopole becomes -1/2!

Numerical analysis

Lattice setup

On a three-dimensional hyper-cubic lattice with size L with open boundary conditions, we put a monopole at $\boldsymbol{x}_m = (L/2, L/2, L/2)$ with a magnetic charge n/2. We also put an antimonopole at $\boldsymbol{x}_a = (L/2, L/2, 1/2)$ with the opposite charge -n/2.



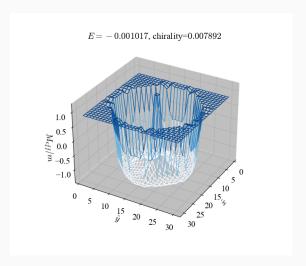
Domain-wall creation

To directly confirm creation of the domain-wall near the monopole, we plot distribution of the "effective mass" (normalized by m_0),

$$m_{\text{eff}}(\boldsymbol{x}) = \phi(\boldsymbol{x})^{\dagger} \left[-\sum_{i=1,2,3} \frac{1}{2} \nabla_i^f \nabla_i^b + m(\boldsymbol{x}) \right] \phi(\boldsymbol{x}) / \phi(\boldsymbol{x})^{\dagger} \phi(\boldsymbol{x}),$$

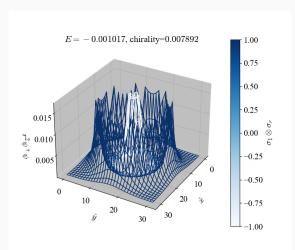
on the z = (L+1)/2 slice.

The effective mass of the nearest zeromode with n=1 on z=16 slice:



Amplitude

The amplitude of the nearest-zero mode for n=1 in z=16 slice:



Summary

We discussed a microscopic description of the Witten effect with the Wilson term.

How do we distinguish between the normal insulator (m > 0) and topological insulator (m < 0)?

- It is the topological insulator if the mass is relatively negative compared to the PV mass.

Why are electrons bound to monopole?

- Because of the positive mass correction from the magnetic field of the monopole, the domain-wall is dynamically created (only for the negative mass).

Why do the stable chiral zero modes appear?

- Because the zero modes localized at the domain-wall are protected by the AS index.

Why is the electric charge fractional?

- Because the 50% of the wavefunction is located around the monopole (the other 50% is located at the surface of the topological insulator).